

# Aberration retrieval using the extended Nijboer-Zernike approach

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**Abstract.** We give the proof of principle of a new experimental method to determine the aberrations of an optical system in the field. The measurement is based on the observation of the intensity point-spread function of the lens. To analyze and interpret the measurement, use is made of an analytical method, the so-called extended Nijboer-Zernike approach. The new method is applicable to lithographic projection lenses, but also to EUV mirror systems or microscopes such as the objective lens of an optical mask inspection tool. Phase retrieval is demonstrated both analytically and experimentally. The extension of the method to the case of a medium-to-large hole sized test object is presented. Theory and experimental results are given. In addition we present the extension to the case of aberrations comprising both phase and amplitude errors.  
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Subject terms: optical lithography; aberrations; phase retrieval; amplitude retrieval; point-spread function; Nijboer-Zernike theory.

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## 1 Introduction

The increased interest in qualification methods for lithographic projection lenses may be explained from a number of factors; projection lens aberrations are known to have an important contribution to linewidth variation and image misplacement.<sup>1,2</sup> Their impact gets more pronounced with each new technology node due to the small dimensions compared to the exposure wavelength, i.e., low  $k_1$  imaging requires tighter aberration specifications. To minimize the impact of aberrations, modern lithographic lenses have a number of manipulators to tune specific aberration terms. Focal plane deviation, astigmatism, coma, and spherical aberration are all adjustable quantities. Although the lens manufacturer delivers a well-optimized lens, the advanced user needs to balance lens aberrations for optimal performance on specific patterns. In addition, aberrations may vary in time due to lens aging and machine drift.

Although several user tests are available such as an *in situ* interferometer<sup>3</sup> or various resist-based methods,<sup>4-6</sup> we have chosen for a different approach. Our approach to determine the lens aberrations, both phase and amplitude, is based on the observation of the intensity point-spread function of the lens, a method that has a number of advantages. The test pattern is the most simple and elementary pattern that exists: an isolated transparent hole in a dark field binary mask. For a sufficiently small hole diameter, small compared to the system resolution, the image will approximate the point-spread function of the lens, which is either

recorded in resist or captured by a detector. Exposing the mask through focus results in the measurement of the 3-D intensity of the point-spread function. It is noted that the point-spread function fully characterizes the lens and is independent of the illumination source. Also, the point-spread function contains the information of both the low- and high-order aberrations. From an experimental point of view the procedure is straightforward. The problematic part is therefore not the experiment, it is the interpretation of the measurement.

To analyze and interpret the measurement, use is made of a new analytical method. The through-focus image intensity of the point-spread function, including the effects of aberrations, is described by a recently found Bessel series representation. This description, called the extended Nijboer-Zernike approach,<sup>7,8</sup> is tailor-made for the inverse problem we have to solve: retrieving the phase defects (aberrations) of the lens from the intensity measurements in the focal region. Following the new approach, the through-focus point-spread function is expressed as a combination of basic functions. The coefficients of these basic functions are identical to the Zernike coefficients that represent the pupil function and are estimated by optimizing the match between the theoretical intensity and the measured intensity patterns at several values of the defocus parameter.

Phase retrieval by the extended Nijboer-Zernike approach is applicable to lithographic projection lenses, but also to EUV mirror systems or microscopes such as the objective lens of an optical mask inspection tool. This pa-

per gives a detailed description of the phase retrieval method and shows the first experimental results, demonstrating the feasibility of our approach. The last section discusses the extension to general aberration retrieval. Here we consider the retrieval of general aberrations  $A \cdot \exp(i\Phi)$  with a possible non-constant pupil transmission amplitude  $A$ . Retrieval of amplitude errors is a unique feature of our method and is worked out in more detail in Ref. 9.

## 2 Basic Formulas for the Computation of the Complex Amplitude of a Point-Spread Function

The point-spread function or impulse response<sup>10</sup> of an optical system is the image of an infinitely small object. In practice an object having a diameter of the order of  $\sim \lambda/2NA$  is a fair approximation. The complex amplitude of a point-spread function is denoted as  $U(x,y)$ . The relationship between normalized image coordinates  $(x,y)$  and the defocus parameter  $f$  and the real space image coordinates  $(X,Y,Z)$  in the lateral and axial direction is given by:

$$x = X \frac{NA}{\lambda}, \quad y = Y \frac{NA}{\lambda} \quad (1)$$

$$r = \sqrt{x^2 + y^2}, \quad (x,y) = (r \cos \phi, r \sin \phi)$$

$$f = 2 \frac{\pi}{\lambda} Z (1 - \sqrt{1 - NA^2}),$$

with  $(r, \phi)$  polar coordinates in the image plane. For a number of special cases the point-spread function is well known. The in-focus ( $f=0$ ), aberration-free amplitude distribution of the point-spread function is the Airy pattern:

$$U(x,y) = 2 \frac{J_1(v)}{v}, \quad v = 2\pi r. \quad (2)$$

A central spot is surrounded by a dark ring corresponding to the first minimum of  $J_1(v)$ . The aberrations of the optical system are described by an aberration function.<sup>9</sup> Without loss of generality, the usual symmetry and normalization assumptions may be made. For small phase defects, the aberration function  $\Phi$  is expanded as a series of Zernike terms<sup>9</sup> involving the polar pupil coordinates  $(\rho, \theta)$ :

$$\Phi = \sum_{nm} \alpha_{nm} R_n^m(\rho) \cos(m\theta), \quad \text{with real } \alpha_{nm},$$

$$0 \leq \theta \leq 2\pi, \quad 0 \leq \rho \leq 1. \quad (3)$$

We use the Fringe Zernike convention to represent the lens aberrations, as shown in Table 1 below.

The in-focus ( $f=0$ ) amplitude distribution in the presence of small aberrations was already given by Nijboer<sup>11</sup> as:

**Table 1** Fringe Zernike convention.

$(n,m)$	Name	$R_n^m(\rho) \cos(m\theta)$	Term
(0,0)	Piston	1	$Z_1$
(1,1)	Tilt	$\rho \cos(\theta)$	$Z_2$
(2,0)	Defocus	$2\rho^2 - 1$	$Z_4$
(2,2)	Astigmatism	$\rho^2 \cos(2\theta)$	$Z_5$
(4,0)	Spherical	$6\rho^4 - 6\rho^2 + 1$	$Z_9$
(3,1)	X-Coma	$(3\rho^3 - 2\rho) \cos(\theta)$	$Z_7$
(3,3)	X-Three point	$\rho^3 \cos(3\theta)$	$Z_{10}$

$$\text{Spherical } U(x,y) \approx 2 \left[ \frac{J_1(v)}{v} + i \alpha_{4,0} \frac{J_5(v)}{v} \right] \quad (4)$$

$$\text{Coma } U(x,y) \approx 2 \left[ \frac{J_1(v)}{v} - \alpha_{3,1} \frac{J_4(v)}{v} \cos \phi \right]$$

$$\text{Astigmatism } U(x,y) \approx 2 \left[ \frac{J_1(v)}{v} - i \alpha_{2,2} \frac{J_3(v)}{v} \cos 2\phi \right]$$

with  $v = 2\pi r$ . According to the extended Nijboer-Zernike theory,<sup>7,8</sup> the complex amplitude of the point-spread function  $U$  is in first-order approximation given by:

$$U \approx 2V_{00} + 2i \sum_{n,m} \alpha_{nm} i^m V_{nm} \cos m\phi, \quad (5)$$

where  $\alpha_{nm}$  are the Zernike coefficients of the single aberrations  $R_n^m(\rho) \cos m\theta$ . For integers  $n, m \geq 0$  with  $n - m \geq 0$  and even, the Bessel series representation for  $V_{nm}$  reads

$$V_{nm}(r,f) = \exp(if) \sum_{l=1}^{\infty} (-2if)^{l-1} \sum_{j=0}^p v_{lj} \frac{J_{m+l+2j}(v)}{lv^l},$$

$$v = 2\pi r, \quad (6)$$

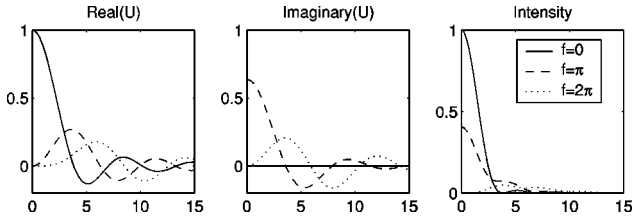
with  $v_{lj}$  given by

$$v_{lj} = (-1)^p (m+l+2j) \binom{m+j+l-1}{l-1} \binom{j+l-1}{l-1} \times \binom{l-1}{p-j} / \binom{q+l+j}{l}, \quad (7)$$

where  $l = 1, 2, \dots; j = 0, \dots, p$ . In Eq. (7) we have set

$$p = \frac{n-m}{2}, \quad q = \frac{n+m}{2}. \quad (8)$$

The special case of  $f=0$  corresponds to Eq. (4). For the number  $L$  of terms to be included in the infinite series over  $l$  the following rule<sup>8</sup> is used: if  $L$  is three times the defocus parameter, the absolute truncation error is of the order  $10^{-6}$ .



**Fig. 1** The through-focus aberration-free amplitude and intensity distribution of the point-spread function. The horizontal axis represents the radial axis in normalized units [see Eq. (1)].

Figure 1 gives a result of the through-focus aberration-free amplitude and intensity distribution of the point-spread function, calculated with Eq. (5).

High-order aberrations, i.e., large values of  $n$  and  $m$  and large defocus values up to  $f = \pm 4\pi$ , provide no problem for the convergence of the series in Eq. (6). The extended Nijboer-Zernike approach is therefore tailor-made for our phase retrieval problem.

## 2.1 Extension to Finite Hole Size

Up to now we have assumed that the diameter of the hole in the binary mask is so small that it can be regarded as a true delta function. From a practical point of view, however, it would be favorable to use holes with a non-negligible diameter since the increased amount of light would significantly reduce the required exposure dose, making the experimental procedure much more practical. We assume that the diameter is small compared to the coherence radius of the illumination source, a condition that is almost always fulfilled. The effect of a non-negligible diameter is a drop in amplitude at the rim of the pupil. In normalized coordinates, this means that the pupil function must be multiplied by the Fourier transform of a disk:

$$\frac{J_1(2\pi a\rho)}{\pi a\rho}, \quad (9)$$

with  $a$  the normalized diameter of the hole. Here one should think of  $a$  as being as large as  $1/\pi$  so that an amplitude drop of some 40% at the rim  $\rho = 1$  of the pupil results from multiplication by the function in Eq. (9). In fact, in the experiments described in Sec. 3.2 we have used holes with a diameter of  $0.6 \mu\text{m}$ , which corresponds to a normalized diameter  $a$  of  $NA/2\pi\lambda \cdot \text{diam} \sim 0.31$ .

The extended Nijboer-Zernike theory is sufficiently flexible to account for this effect.<sup>12</sup> Here one approximates

$$\frac{J_1(2\pi a\rho)}{\pi a\rho} \approx \exp(c - d\rho^2), \quad (10)$$

with optimal  $c, d$ , and the  $V_{nm}(r, f)$  of Eq. (6) should be replaced throughout by

$$\exp(c)V_{nm}(r, f + id). \quad (11)$$

As one sees from Eq. (6), nothing prevents us from using the Bessel series representation with complex defocus parameter  $f + id$ . The optimal  $c, d$  in Eq. (10) are accurately given as a function of  $b = 2\pi a$  by

$$c = \frac{b^4}{2304} + \frac{b^6}{46080}, \quad d = \frac{b^2}{8} + \frac{b^4}{384} + \frac{b^6}{10240}. \quad (12)$$

A similar correction can be carried out in the case where the conventional approximation  $\exp(if\rho^2)$ , describing defocusing in the diffraction integral, is no longer adequate due to high numerical aperture (see Ref. 9 for further details). Accordingly, the application range of the method is extended from  $NA$  of around 0.65 to  $NA$  up to 0.85. Figure 2 shows a comparison of the extended Nijboer-Zernike theory and a commercial lithographic simulator (SOLID-C<sup>13</sup>). As an example we chose an aberration-free lens, two settings of the numerical aperture  $NA = 0.6$  and  $NA = 0.80$  and two diameters of  $0.1 \mu\text{m}$  and  $0.3 \mu\text{m}$ . The intensity deviations between the analytical computation and the Solid-C full vectorial, unpolarized calculation has a standard deviation typical of the order of  $\sim 1\%$ . A detailed assessment and additional examples can be found elsewhere.<sup>8,12</sup>

## 2.2 Determination of the Zernike Coefficient: Phase Retrieval

There is a considerable amount of literature on the problem of phase retrieval from intensity measurements with or without focus variation.<sup>14</sup> The method we describe below has the following new features. In the first place, the method is analytical in nature and uses some parts of linear algebra. The resulting linear systems for the aberration coefficients are generically well-conditioned due to near-orthogonality of the relevant basic functions. This near-orthogonality is brought about by consideration of a whole range of defocus values.

The observed quantity is the *image intensity*  $I(x, y, f) = |U(x, y, f)|^2$ . Usually the image intensity is measured using rectangular coordinates. The first step is to transform the observed image intensity to polar coordinates  $I(r, \phi, f)$ . Using Eq. (5), the intensity is in a first-order approximation:

$$I \approx 4|V_{00}|^2 + 8 \sum_{nm} \alpha_{nm} \text{Re}\{i^{m+1}V_{00}^*V_{nm}\} \cos m\phi. \quad (13)$$

It is our task to estimate the Zernike coefficients  $\alpha_{nm}$  from  $I$ .

A Fourier analysis with respect to the angular dependence of the observed image intensity is made:

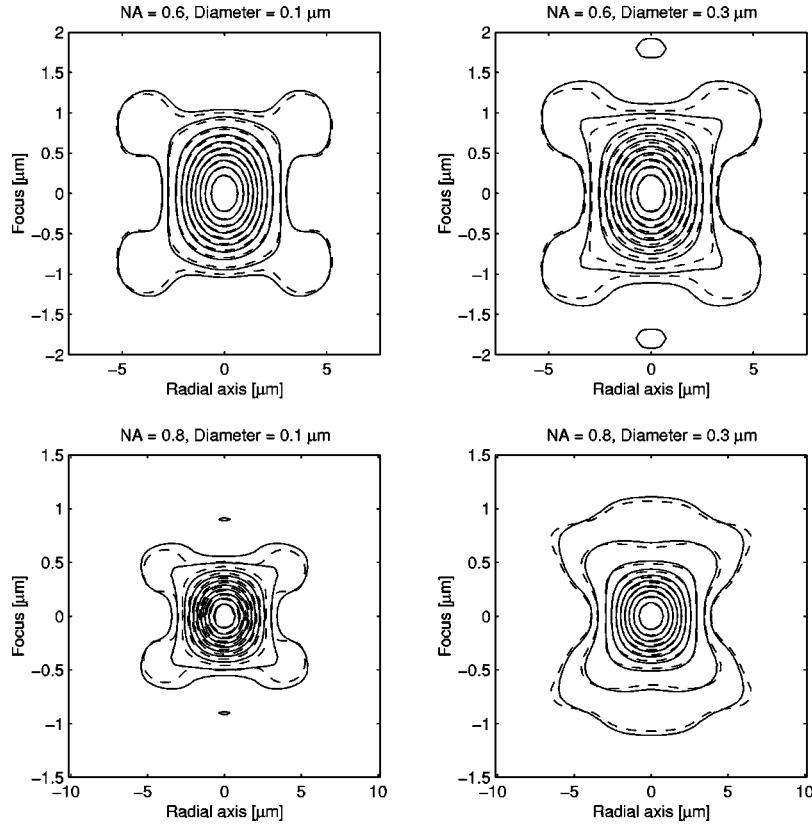
$$\Psi^m(r, f) = \frac{1}{2\pi} \int_0^{2\pi} I(r, \phi, f) \cos m\phi d\phi. \quad (14)$$

An inner product is defined in the  $(r, f)$  space:

$$(\Psi, \chi) = \int_0^R \int_{-F}^F r \cdot \Psi(r, f) \cdot \chi(r, f)^* dr df. \quad (15)$$

We denote:

$$\Psi_n^m(r, f) = \gamma_m \text{Re}\{i^{m+1}V_{00}^*V_{nm}\}, \quad (16)$$



**Fig. 2** The intensity point-spread function of an aberration-free lens for various values of the numerical aperture and hole size. The extended Nijboer-Zernike theory (dashed lines) is compared with a commercial lithographic simulator (solid lines). The deviations are typically 1%.

with  $\gamma_m = 4$ ,  $m = 1, 2, \dots$ ,  $\gamma_0 = 8$ . Then by multiplying Eq. (13) by  $\cos m\phi$  and integrating over  $\phi$ , the  $m$ 'th harmonic of the observed intensity is expressed as a linear sum of the  $\Psi_n^m(r, f)$  functions with coefficients  $\alpha_{nm}$ :

$$\sum_n \alpha_{nm} \Psi_n^m(r, f) \approx \Psi^m(r, f), \quad (17)$$

which is a near identity between measured quantities on the right and theoretical quantities on the left. By taking the inner product, defined above, of Eq. (17) with  $\Psi_{n'}^m$ , the Zernike coefficients can be estimated on solving a linear system of equations:

$$\sum_n \alpha_{nm} (\Psi_n^m, \Psi_{n'}^m) = (\Psi^m, \Psi_{n'}^m). \quad (18)$$

By restricting the number of the  $n'$  at the right-hand side and the summation at the left-hand side of Eq. (17) to  $M$  terms, the linear combination of the  $\Psi_n^m$ , obtained by solving the  $M \times M$  linear system, gives the least square approximation of  $\Psi^m$  as a linear combination of the  $\Psi_n^m$ . The solution is the best linear combination that one can obtain from the experimentally observed intensity profile using  $M$  terms in Eq. (17).

### 2.3 Validating the Phase Retrieval Capabilities

In this subsection we discuss the retrieving capabilities of the extended Nijboer-Zernike theory. As an example we calculate the complex amplitude in the presence of low-order coma  $\alpha_{31} = 0.05$  using Eq. (5); it is assumed that the first-order approximation of the complex amplitude is valid. Then we show that phase retrieval is exact. The problem we have to solve is how to retrieve the phase defect, i.e.,  $\alpha_{31}$ , from the 3-D image intensity.

Following the phase retrieval recipe discussed above, the first step is to form the linear system. In our example we use the first three coma terms  $n = 1, 3, 5$  to describe the aberrations of the point-spread function:

$$\alpha_{1,1}(\Psi_1^1, \Psi_1^1) + \alpha_{3,1}(\Psi_3^1, \Psi_1^1) + \alpha_{5,1}(\Psi_5^1, \Psi_1^1) = (\Psi^1, \Psi_1^1) \quad (19)$$

$$\alpha_{1,1}(\Psi_1^1, \Psi_3^1) + \alpha_{3,1}(\Psi_3^1, \Psi_3^1) + \alpha_{5,1}(\Psi_5^1, \Psi_3^1) = (\Psi^1, \Psi_3^1)$$

$$\alpha_{1,1}(\Psi_1^1, \Psi_5^1) + \alpha_{3,1}(\Psi_3^1, \Psi_5^1) + \alpha_{5,1}(\Psi_5^1, \Psi_5^1) = (\Psi^1, \Psi_5^1)$$

with  $\Psi^1$  the measured first harmonic and  $\Psi_1^1 \cdot \dots \cdot \Psi_5^1$  the calculated inner product. Next we explicitly calculate the inner products, properly discretizing Eq. (15), and we obtain the linear system:

$$+ 1411 \alpha_{1,1} - 236 \alpha_{3,1} - 41 \alpha_{5,1} = -11.8 \quad (20)$$

**Table 2** Simulated phase retrieval.

Name	Term	$n$	$m$	Zernike coefficients	
	Input aberrations			Retrieved	
Tilt	$Z_2$	1	1	0.0175	0.0175
Defocus	$Z_4$	2	0	-0.0187	-0.0187
Astigmatism	$Z_5$	2	2	0.0726	0.0726
Coma	$Z_7$	3	1	-0.0588	-0.0588
Spherical	$Z_9$	4	0	0.2183	0.2183
Three-point	$Z_{10}$	3	3	-0.0136	-0.0136
Astigmatism	$Z_{12}$	4	2	0.0114	0.0114
Coma	$Z_{14}$	5	1	0.1067	0.1067
Spherical	$Z_{16}$	6	0	0.0059	0.0059

$$-236 \alpha_{1,1} + 320 \alpha_{3,1} - 79 \alpha_{5,1} = +16$$

$$-41 \alpha_{1,1} - 79 \alpha_{3,1} + 103 \alpha_{5,1} = -3.9$$

The magnitude of the inner products depend on the sampling scheme in the  $(r, f)$  space. The solution of Eq. (20) is:

$$\alpha_{1,1} = 0, \quad \alpha_{3,1} = 0.05, \quad \alpha_{5,1} = 0, \quad (21)$$

exactly matching the input.

In the next example we used a set of 40 random aberration coefficients  $\alpha_{nm}$  for input, as shown in Table 2.

Using Eq. (5) we calculated the complex amplitude and the image intensity. The phase retrieval procedure is applied and a *perfect reconstruction* results.

Why does phase retrieval using the extended Nijboer-Zernike approach work so well? The basic functions  $V_{00}^* V_{nm}$  are nearly orthogonal and the matrix to solve Zernike coefficients, similar to Eq. (20), is well conditioned. The perfect reconstruction results, provided sufficient  $(n, m)$  terms are taken into account. Equations (5) and (13) suggest that we have neglected the quadratic intensity term in determining the Zernike coefficients. This is not the case. One can show that the quadratic terms are orthogonal to the linear terms with respect to their dependence on  $f$  and

therefore cancel on forming the linear systems for the coefficients  $\alpha_{nm}$  in Eq. (18). In a similar fashion the quadratic term in expanding the complex aberration amplitude does not show up in the linear system. With respect to the sensitivity to measurement noise, a preliminary simulation showed a satisfactory result; this is to be expected from the well-conditionedness of the linear systems and the large data sizes. These points and a further mathematical underpinning of the method are presented elsewhere.<sup>12</sup>

### 3 Experimental Results

#### 3.1 Microlithography Simulation Microscope Results

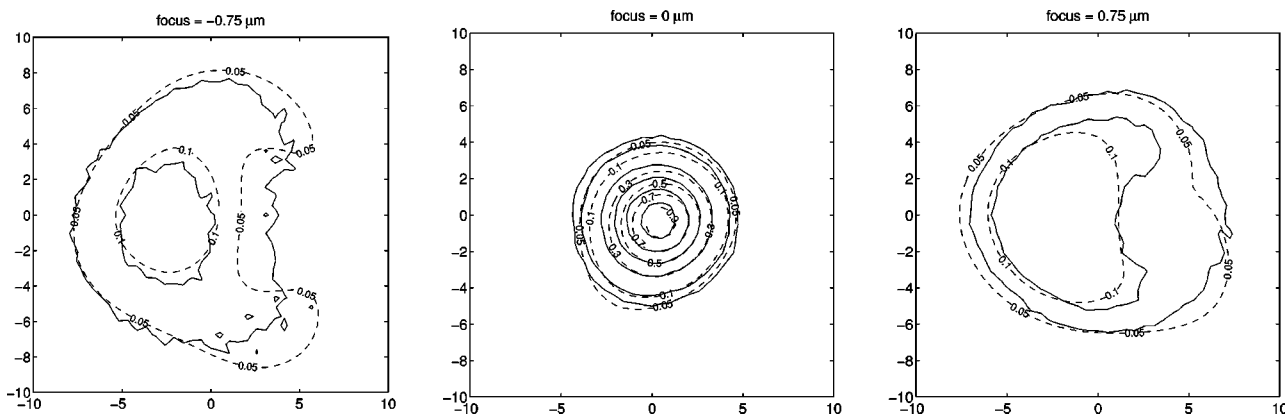
The microlithography simulation microscope (MSM 100)<sup>15</sup> emulates the optics of a scanner and is used for the evaluation of mask defects and optimization of lithographic processes. The MSM 100 microscope is set to emulate a  $\lambda = 193$  nm,  $NA = 0.75$  scanner. The acquired through-focus aerial images of the isolated hole are transferred to an off-line computer for evaluation using homemade software.

We retrieved the Zernike coefficients as described in the previous section. As a check, we calculated the image intensity using the retrieved Zernike coefficients and compared it with the experimental image intensity as shown in Fig. 3. The dominant aberration is 5th-order X-coma, which is clearly visible in the extreme defocus positions.

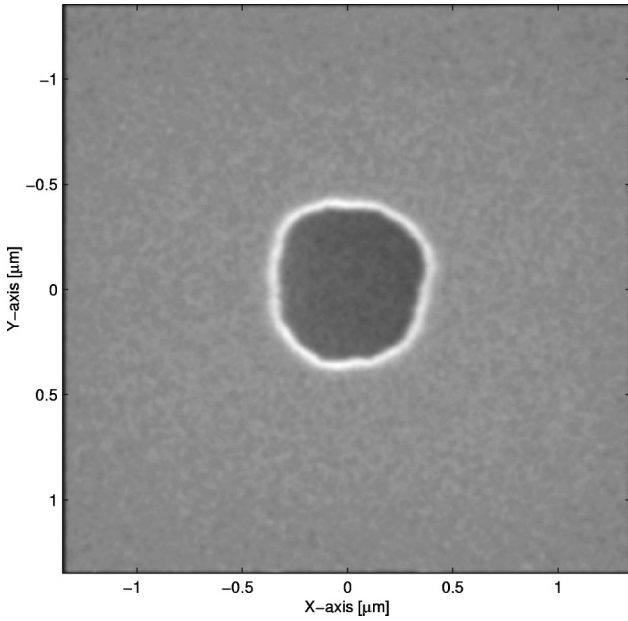
#### 3.2 Lithographic Projection Lens

Getting an electronic version of the point-spread function of a scanner is somewhat more complicated. Image sensors are usually line detectors with relative broad lines having only two orientations. Even if multiple orientations would have been available, the procedure to reconstruct a point-spread function out of the image sensor signal, which essentially integrates perpendicular to the line direction, is a nontrivial procedure. Therefore we have chosen a resist-based experiment.

The reticle, shown in Fig. 4, is a simple chrome on quartz reticle with a  $4 \times 0.15 = 0.6 \mu\text{m}$  transparent hole. An ASML PAS5500/950 system with a  $\lambda = 193$  nm,  $NA = 0.63$  projection lens is used to image the reticle onto resist on a *SiON* antireflective coating. Using *SiON* instead

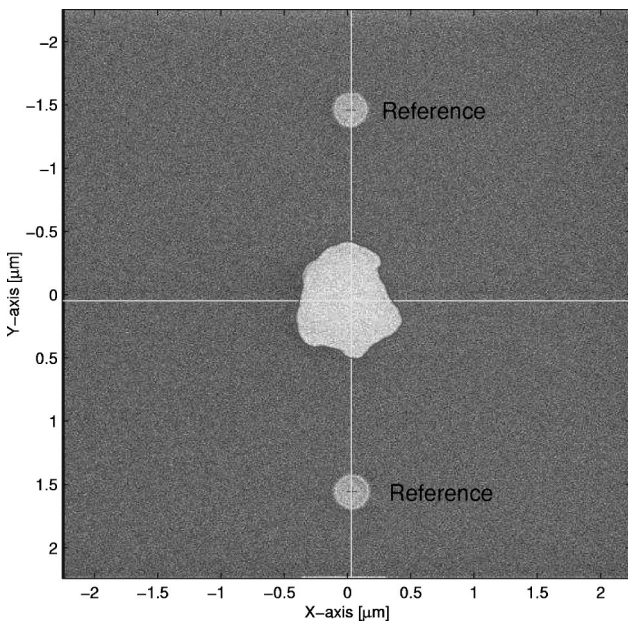


**Fig. 3** Cross sections of the MSM 100 point-spread function at various focus levels. Solid lines represent the experimental data and the dashed lines are calculated using the retrieved Zernike coefficients. High-order X-coma is the dominant aberration. The  $(X, Y)$  axes are in normalized radial units [see Eq. (1)].



**Fig. 4** SEM image of a chrome on quartz reticle with an isolated hole, with a  $0.6 \mu\text{m}$ -diameter, used in our phase retrieval experiments.

of an organic antireflective coating has the advantage that it provides a good contrast in the SEM. First two small reference marks are exposed, using the same reticle. The coordinate system, superimposed onto the image, is shown. The relative large central image in Fig. 5 represents a single contour of the point-spread function at a certain exposure dose and defocus value. Inside this contour, the image intensity is above the resist threshold value and the resist completely develops away, leaving the *SiON* layer. Outside the contour, the SEM image shows the undeveloped resist.



**Fig. 5** SEM image of an exposure onto resist. First two reference marks are exposed defining the coordinate system. The central image represents a single contour of the point-spread function.

The procedure is repeated for a number of focus and exposure dose settings, i.e., the reticle is exposed in a focus exposure matrix (FEM). A SEM, under job control, collects all images. The data reduction is done off-line. All contours are combined into a through-focus aerial image from which the projection lens aberrations are determined as described above. Figure 6 shows the calculated image intensity using the retrieved Zernike coefficients compared to the experimental image intensity. The dominant terms are low-order astigmatism and low order three-point.

### 3.3 Outlook: Extension to General Aberration Retrieval

A further extension concerns the retrieval of a general aberration  $A \cdot \exp(i\Phi)$  with a possible non-constant transmission amplitude  $A$ . Now one expands

$$A \cdot \exp(i\Phi) = \sum_{n,m} \beta_{nm} R_n^m(\rho) \cos m\theta,$$

$$0 \leq \theta \leq 2\pi, \quad 0 \leq \rho \leq 1, \quad (22)$$

where we now aim at estimation of the  $\beta$  coefficients. In a case where  $A \equiv 1$  and  $\Phi$  has been expanded as in Eq. (3), one would get [under the assumption that  $\Phi$  is so small that  $\exp(i\Phi)$  may be linearized]

$$\beta_{nm} = \delta_n \delta_m + i\alpha_{nm} \quad (23)$$

where  $\delta$  is Kronecker's delta. In general, we may assume that  $\beta_{00}$  is positive and large compared to the other  $\beta_{nm}$ 's. Now instead of Eq. (13) we get

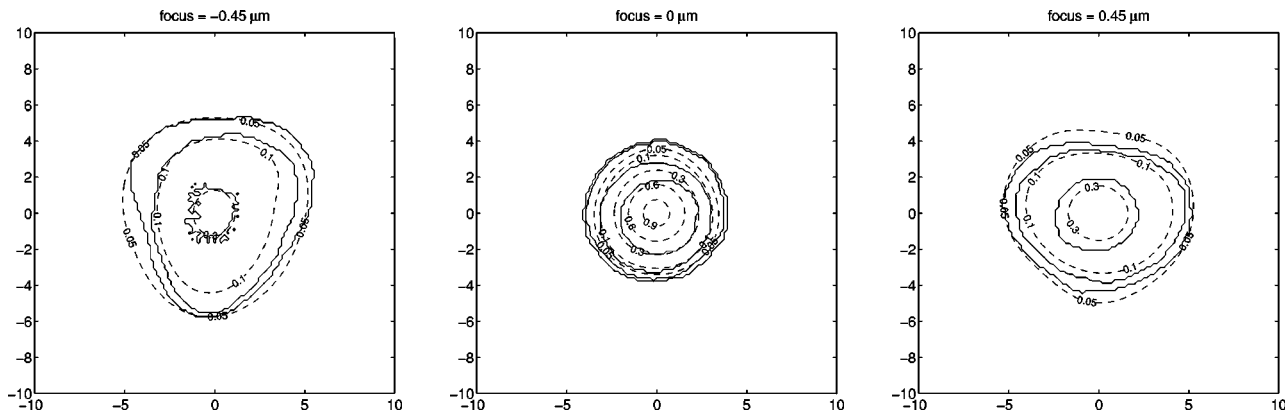
$$I \approx 4\beta_{0,0}^2 |V_{00}|^2 + \beta_{0,0} \sum_{(n,m) \neq (0,0)} \text{Im}(\beta_{nm}) \Psi_n^m \cos m\phi \quad (24)$$

$$+ \beta_{0,0} \sum_{(n,m) \neq (0,0)} \text{Re}(\beta_{nm}) \chi_n^m \cos m\phi.$$

Here we have, in addition to the  $\Psi_n^m$  in Eq. (16), introduced the basic functions

$$\chi_n^m(r, f) = \gamma_m \text{Re}\{i^m V_{00}^* V_{nm}\}. \quad (25)$$

Note that we now have to solve for both  $\text{Im}(\beta_{nm})$  and  $\text{Re}(\beta_{nm})$ . It turns out that the two corresponding linear systems decouple. These systems are obtained by integration over  $\phi$  as in Eq. (14) and taking inner products with  $\Psi_{m'}^m$  and  $\chi_{m'}^m$ , and it now happens that  $\Psi_{m'}^m$  and  $\chi_{m'}^m$  have opposite parity with respect to their dependence on  $f$  so that their inner product vanishes. When in the presence of both amplitude and phase errors, two sets of linear equations must be solved instead of one. The solution is the set of  $\beta_{nm}$  coefficients that must be converted to the amplitude and phase errors using Eq. (22). Retrieval of phase and transmission is feasible and a further analysis of this extension is discussed elsewhere.<sup>12</sup> Note that the pure-phase



**Fig. 6** The point-spread function of a scanner reconstructed from resist images. Solid lines represent the experimental data and the dashed lines are calculated using the retrieved Zernike coefficients. Low-order astigmatism and low-order three-point are the dominant aberrations. The  $(X, Y)$  axes are in normalized radial units [see Eq. (1)].

retrieval method and the general aberration retrieval method use the same set of data.

Observe that the method as presented in Sec. 2.2 is considerably simpler and works directly in terms of optical relevant parameters  $\alpha_{nm}$ , i.e., the Zernike coefficients. However, its applicability is restricted to the cases that we may assume negligible amplitude errors.

#### 4 Discussion

In this paper we have given the proof of principle of a new experimental method to determine the aberrations of an optical system in the field. The measurement is based on the observation of the intensity point-spread function of the lens and uses an analytical method, the so-called extended Nijboer-Zernike approach, for analysis and interpretation of the measurement. The new method is applicable to lithographic projection lenses, but also to microscopes such as the objective lens of an optical mask inspection tool. Phase retrieval was demonstrated both analytically and experimentally. Extension of the method to the case of a medium-to-large hole sized test object as well as to the case of aberrations comprising both phase and amplitude errors was presented. These features make our method suitable for the characterization of future-generation high numerical aperture tools.

#### Acknowledgments

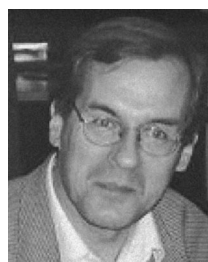
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